

High temperature 4 A sensitive TRIACs

Features

- Medium current TRIAC
- Logic level sensitive TRIAC
- 150 °C max. T_i turn-off commutation
- Clip bounding
- RoHS (2002/95/EC) compliant package

Applications

- The T410H is designed for the control of AC actuators in appliances and industrial systems.
- The multi-port drive of the microcontroller can control the multiple loads of such appliances and systems through this sensitive gate TRIAC.

Description

Specifically designed to operate at 150 °C, the new 4 A T410H TRIAC provides an enhanced performance in terms of power loss and thermal dissipation. This allows the optimization of the heatsink size, leading to space and cost effectiveness when compared to electromechanical solutions.

Based on ST logic level technology, the T410H offers an I_{GT} lower than 10 mA and specified minimal commutation and high noise immunity levels valid up to the T_i max.

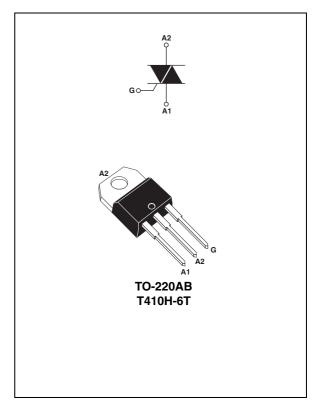


Table 1. Device summary

| Symbol | Value | Unit |
|------------------------------------|-------|------|
| I _{T(RMS)} | 4 | Α |
| V _{DRM} /V _{RRM} | 600 | V |
| I _{GT MAX} | 10 | mA |

Characteristics T410H

1 Characteristics

Table 2. Absolute maximum ratings

| Symbol | Parameter | | | Value | Unit | |
|------------------------------------|--|------------------------|-------------------------|---|------------------|--|
| I _{T(RMS)} | On-state rms current (full sine wave) $T_c = 141 ^{\circ}\text{C}$ | | 4 | Α | | |
| 1. | Non repetitive surge peak on-state current | F = 60 Hz | t = 16.7 ms | 42 | Α | |
| TSM | (full cycle, T _j initial = 25 °C) | | t = 20 ms | 40 | A | |
| l ² t | I't Value for fusing | t _p = 10 ms | | 11 | A ² s | |
| dl/dt | Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$ | F = 120 Hz | T _j = 150 °C | 50 | A/μs | |
| V _{DSM} /V _{RSM} | Non repetitive surge peak off-state voltage | t _p = 10 ms | T _j = 25 °C | V _{DRM} /V _{RRM} + 100 | V | |
| I _{GM} | Peak gate current $t_p = 20 \mu s$ $T_j =$ | | T _j = 150 °C | 4 | Α | |
| P _{G(AV)} | Average gate power dissipation $T_j = 150 ^{\circ}\text{C}$ | | 1 | W | | |
| T _{stg} T _j | Storage junction temperature range Operating junction temperature range | | | - 40 to + 150 - 40 to + 150 | °C | |

Table 3. Electrical characteristics ($T_i = 25$ °C, unless otherwise specified)

| Symbol | Test conditions | Quadrant | Min. | Max. | Unit |
|-------------------------------|---|--------------|------|------|------|
| I _{GT} | V - 12 V B - 22 O | 1 - 11 - 111 | 1 | 10 | mA |
| V _{GT} | $V_D = 12 \text{ V} R_L = 33 \Omega$ | 1 - 11 - 111 | | 1.0 | V |
| V_{GD} | $V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ | 1 - 11 - 111 | 0.15 | | V |
| I _H ⁽¹⁾ | I _T = 100 mA | | | 25 | mA |
| | 1.01 | I - III | | 30 | mA. |
| Ι _L | $I_{G} = 1.2 I_{GT}$ | II | | 35 | IIIA |
| dV/dt (1) | V _D = 67% V _{DRM,} gate open, T _j = 150 °C | | 75 | | V/µs |
| (dl/dt)c ⁽¹⁾ | Logic level, 0.1 V/μs, T _j = 150 °C | | 5.7 | | A/ms |
| (ui/ut)C · / | Logic level, 15 V/µs, T _j = 150 °C | | 1.5 | | |

^{1.} For both polarities of A2 referenced to A1.

T410H Characteristics

Table 4. Static characteristics

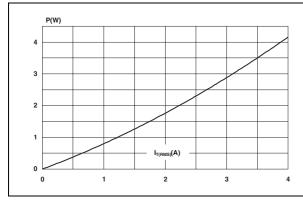
| Symbol | Test conditions | | | Value | Unit | |
|-------------------------------|--|-------------------------|------|-------|------|--|
| V _T ⁽¹⁾ | $I_{TM} = 5.6 \text{ A}, t_p = 380 \ \mu\text{s}$ | T _j = 25 °C | MAX. | 1.5 | V | |
| V _{t0} (1) | Threshold voltage | T _j = 150 °C | MAX. | 0.80 | V | |
| R _d ⁽¹⁾ | Dynamic resistance | T _j = 150 °C | MAX. | 80.0 | mΩ | |
| | V V | T _j = 25 °C | MAX. | 5 | μA | |
| I _{DRM} | $V_{DRM} = V_{RRM}$ | T _j = 150 °C | MAX. | 2.2 | | |
| I _{RRM} | V _D /V _R = 400 V (at peak mains voltage) | T _j = 150 °C | MAX. | 1.75 | mA | |
| | V _D /V _R = 200 V (at peak mains voltage) | T _j = 150 °C | MAX. | 1.5 | | |

^{1.} for both polarities of A2 referenced to A1.

Table 5. Thermal resistance

| Symbol | Parameter | Value | Unit |
|----------------------|-----------------------|-------|------|
| R _{th(j-c)} | Junction to case (AC) | 2.20 | °C/W |
| R _{th(j-a)} | Junction to ambient | 60 | C/VV |

Figure 1. Maximum power dissipation versus Figure 2. On-state rms current versus case on-state rms current (full cycle) temperature (full cycle)



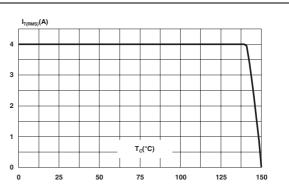
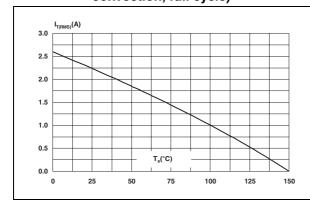
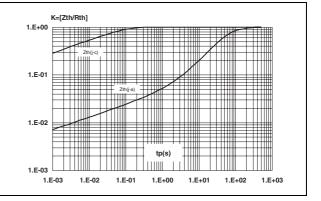


Figure 3. On-state rms current versus ambient temperature (free air convection, full cycle)

Figure 4. Relative variation of thermal impedance, versus pulse duration





Characteristics T410H

Figure 5. Relative variation of gate trigger current and voltage versus junction temperature (typical values)

Figure 6. Relative variation of holding and latching current versus junction temperature (typical values)

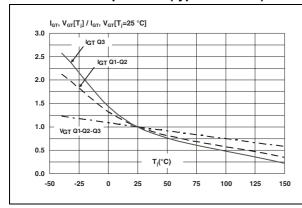
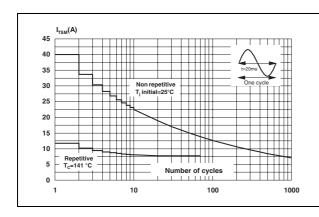


Figure 7. Surge peak on-state current versus number of cycles

Figure 8. Non-repetitive surge peak on-state current and corresponding value of I²t



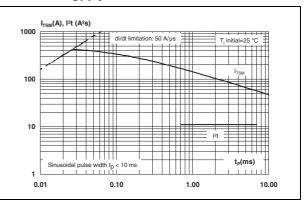
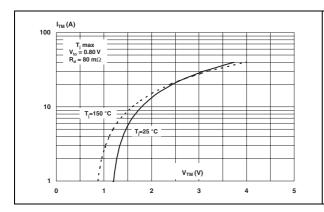
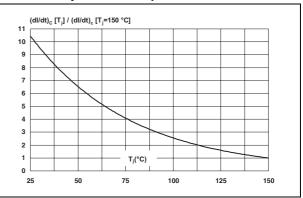


Figure 9. On-state characteristics (maximum values)

Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature



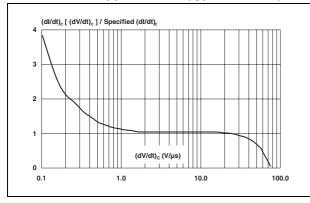


T410H **Characteristics**

Relative variation of critical rate of Figure 12. decrease of main current versus reapplied dV/dt (typical values)

immunity versus junction temperature dV/dt [T $_{\rm j}$] / dV/dt [T $_{\rm j}$ =150 °C] 14 13 V_D=V_R=400 V _ 12 11

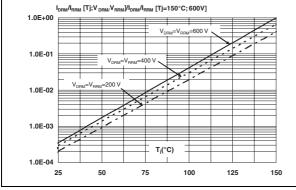
Relative variation of static dV/dt

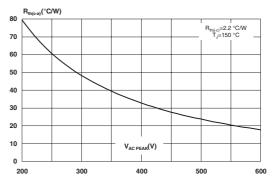


T_j(°C) 25 50 75 100

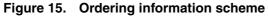
Figure 13. Variation of leakage current versus Figure 14. Acceptable case to ambient thermal junction temperature for different values of blocking voltage

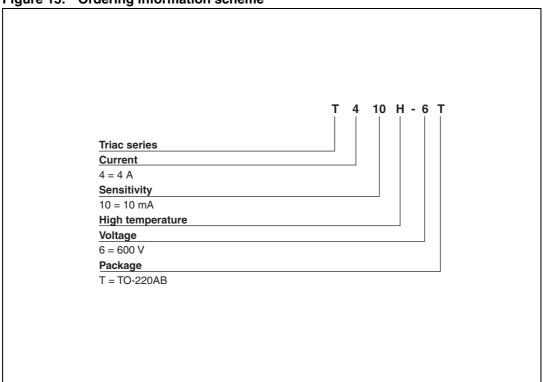
resistance versus repetitive peak off-state voltage 80





2 Ordering information scheme





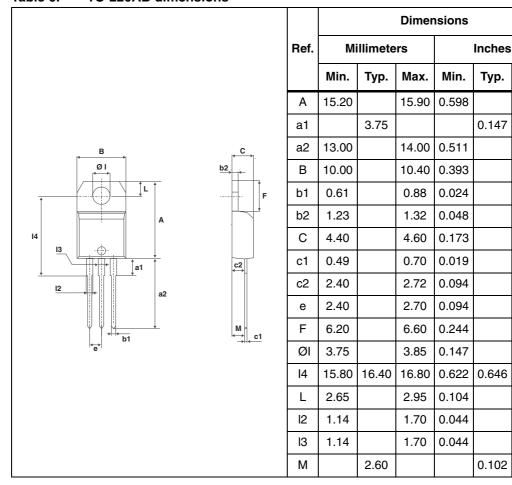
T410H Package information

3 Package information

- Epoxy meets UL94, V0
- Recommended torque 0.4 to 0.6 N⋅m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 6. TO-220AB dimensions



Max.

0.625

0.551

0.409

0.034

0.051

0.181

0.027

0.107

0.106

0.259

0.151

0.661

0.116

0.066

0.066

Ordering information T410H

4 Ordering information

Table 7. Ordering information

| Order code | Marking | Package | Weight | Base qty | Delivery mode |
|------------|----------|----------|--------|----------|---------------|
| T410H-6T | T410H 6T | TO-220AB | 2.3 g | 50 | Tube |

5 Revision history

Table 8. Document revision history

| Date | Revision | Changes |
|-------------|----------|--------------|
| 15-May-2009 | 1 | First issue. |

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